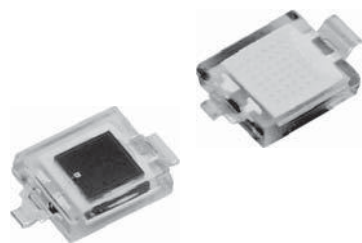
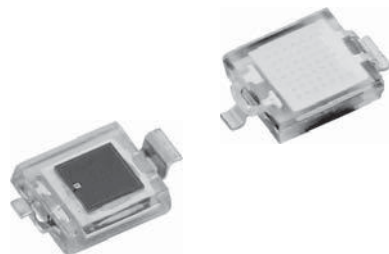


Silicon PIN Photodiode



VBP104S



VBP104SR

FEATURES

- Package type: surface mount
- Package form: GW, RGW
- Dimensions (L x W x H in mm): 6.4 x 3.9 x 1.2
- Radiant sensitive area (in mm²): 4.4
- High photo sensitivity
- High radiant sensitivity
- Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity: $\phi = \pm 65^\circ$
- Floor life: 168 h, MSL 3, acc. J-STD-020
- Lead (Pb)-free reflow soldering
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC


RoHS
COMPLIANT

DESCRIPTION

VBP104S and VBP104SR are high speed and high sensitive PIN photodiodes. It is a surface mount device (SMD) including the chip with a 4.4 mm² sensitive area detecting visible and near infrared radiation.

APPLICATIONS

- High speed photo detector

PRODUCT SUMMARY

COMPONENT	I_{ra} (μA)	ϕ (deg)	$\lambda_{0.1}$ (nm)
VBP104S	35	± 65	430 to 1100
VBP104SR	35	± 65	430 to 1100

Note

- Test conditions see table "Basic Characteristics"

ORDERING INFORMATION

ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
VBP104S	Tape and reel	MOQ: 1000 pcs, 1000 pcs/reel	Gullwing
VBP104SR	Tape and reel	MOQ: 1000 pcs, 1000 pcs/reel	Reverse gullwing

Note

- MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25^\circ\text{C}$, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V_R	60	V
Power dissipation	$T_{amb} \leq 25^\circ\text{C}$	P_V	215	mW
Junction temperature		T_j	100	$^\circ\text{C}$
Operating temperature range		T_{amb}	- 40 to + 100	$^\circ\text{C}$
Storage temperature range		T_{stg}	- 40 to + 100	$^\circ\text{C}$
Soldering temperature	Acc. reflow solder profile fig. 8	T_{sd}	260	$^\circ\text{C}$
Thermal resistance junction/ambient		R_{thJA}	350	K/W

**BASIC CHARACTERISTICS** (T_{amb} = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 50 mA	V _F		1	1.3	V
Breakdown voltage	I _R = 100 μA, E = 0	V _(BR)	60			V
Reverse dark current	V _R = 10 V, E = 0	I _{ro}		2	30	nA
Diode capacitance	V _R = 0 V, f = 1 MHz, E = 0	C _D		48		pF
	V _R = 3 V, f = 1 MHz, E = 0	C _D		17	40	pF
Open circuit voltage	E _e = 1 mW/cm ² , λ = 950 nm	V _o		350		mV
Temperature coefficient of V _o	E _e = 1 mW/cm ² , λ = 950 nm	TK _{V_o}		- 2.6		mV/K
Short circuit current	E _e = 1 mW/cm ² , λ = 950 nm	I _k		32		μA
Temperature coefficient of I _k	E _e = 1 mW/cm ² , λ = 950 nm	TK _{I_k}		0.1		%/K
Reverse light current	E _e = 1 mW/cm ² , λ = 950 nm, V _R = 5 V	I _{ra}	25	35		μA
Angle of half sensitivity		φ		± 65		deg
Wavelength of peak sensitivity		λ _p		940		nm
Range of spectral bandwidth		λ _{0.1}		430 to 1100		nm
Noise equivalent power	V _R = 10 V, λ = 950 nm	NEP		4 x 10 ⁻¹⁴		W/√Hz
Rise time	V _R = 10 V, R _L = 1 kΩ, λ = 820 nm	t _r		100		ns
Fall time	V _R = 10 V, R _L = 1 kΩ, λ = 820 nm	t _f		100		ns

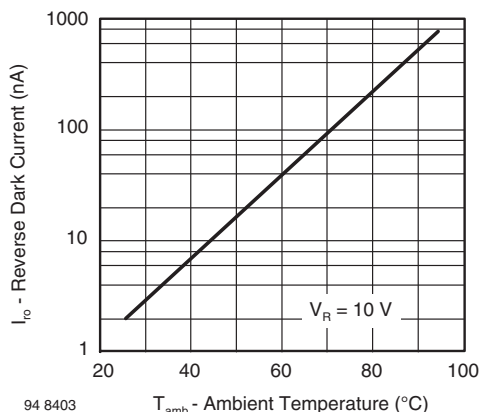
BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

Fig. 1 - Reverse Dark Current vs. Ambient Temperature

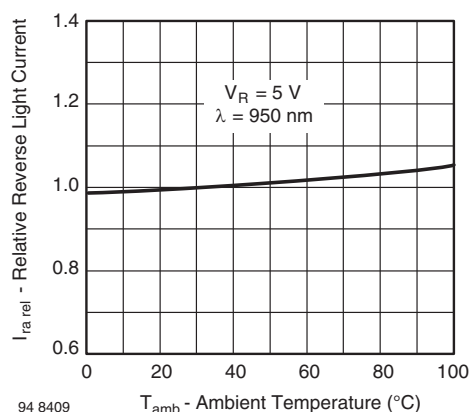


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

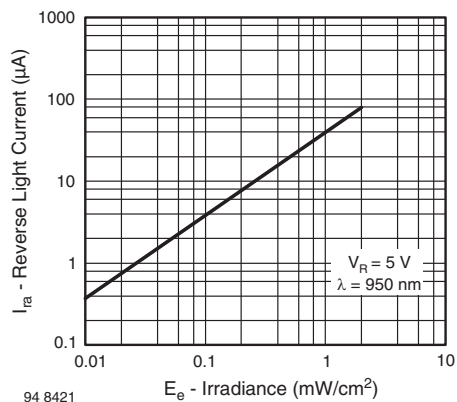


Fig. 3 - Reverse Light Current vs. Irradiance

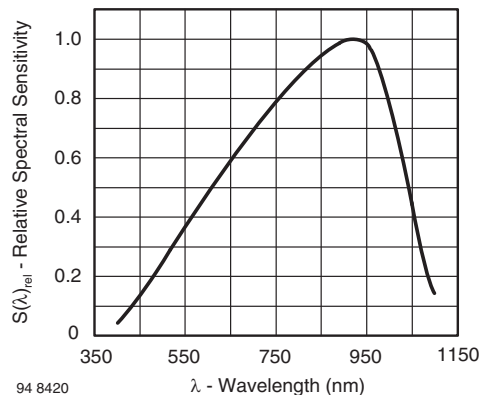


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

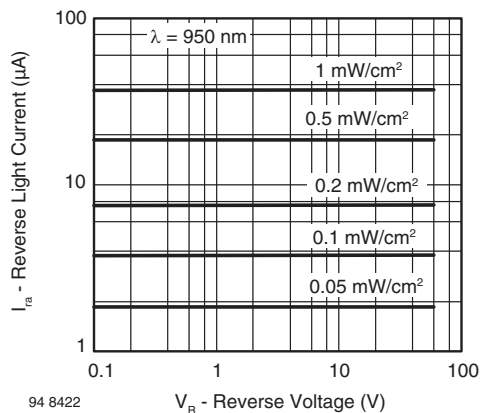


Fig. 4 - Reverse Light Current vs. Reverse Voltage

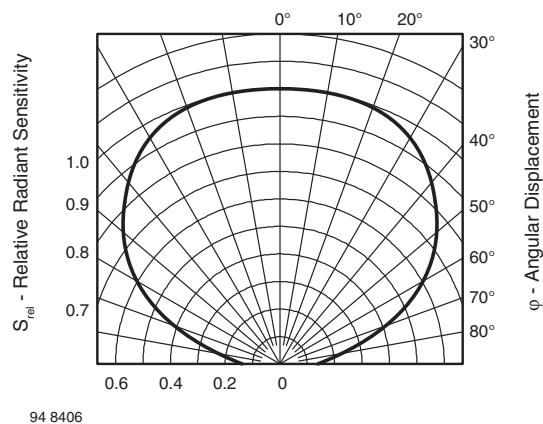


Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement

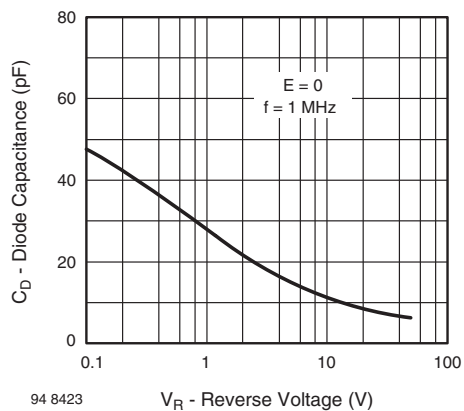
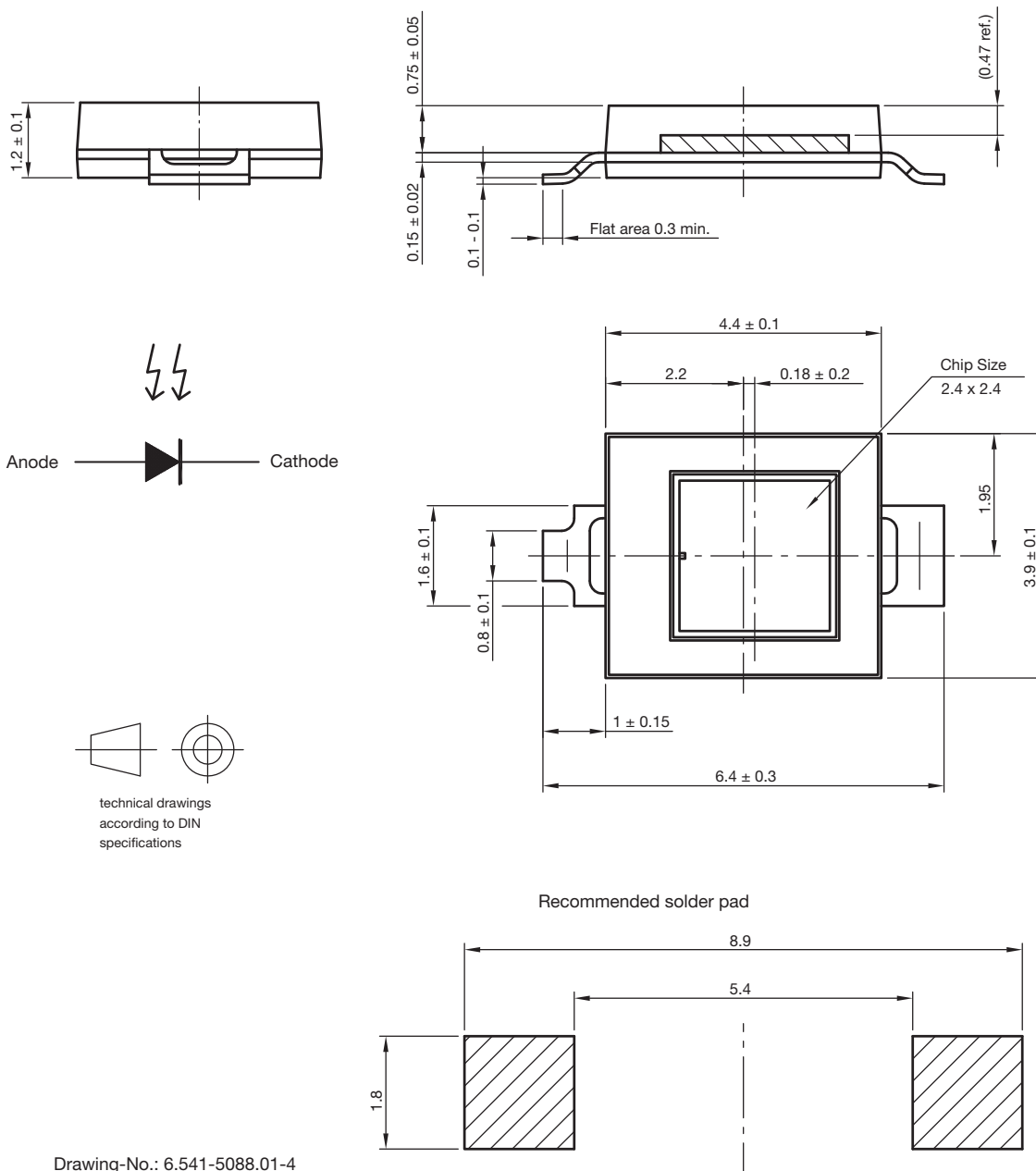


Fig. 5 - Diode Capacitance vs. Reverse Voltage



PACKAGE DIMENSIONS FOR VBP104S in millimeters



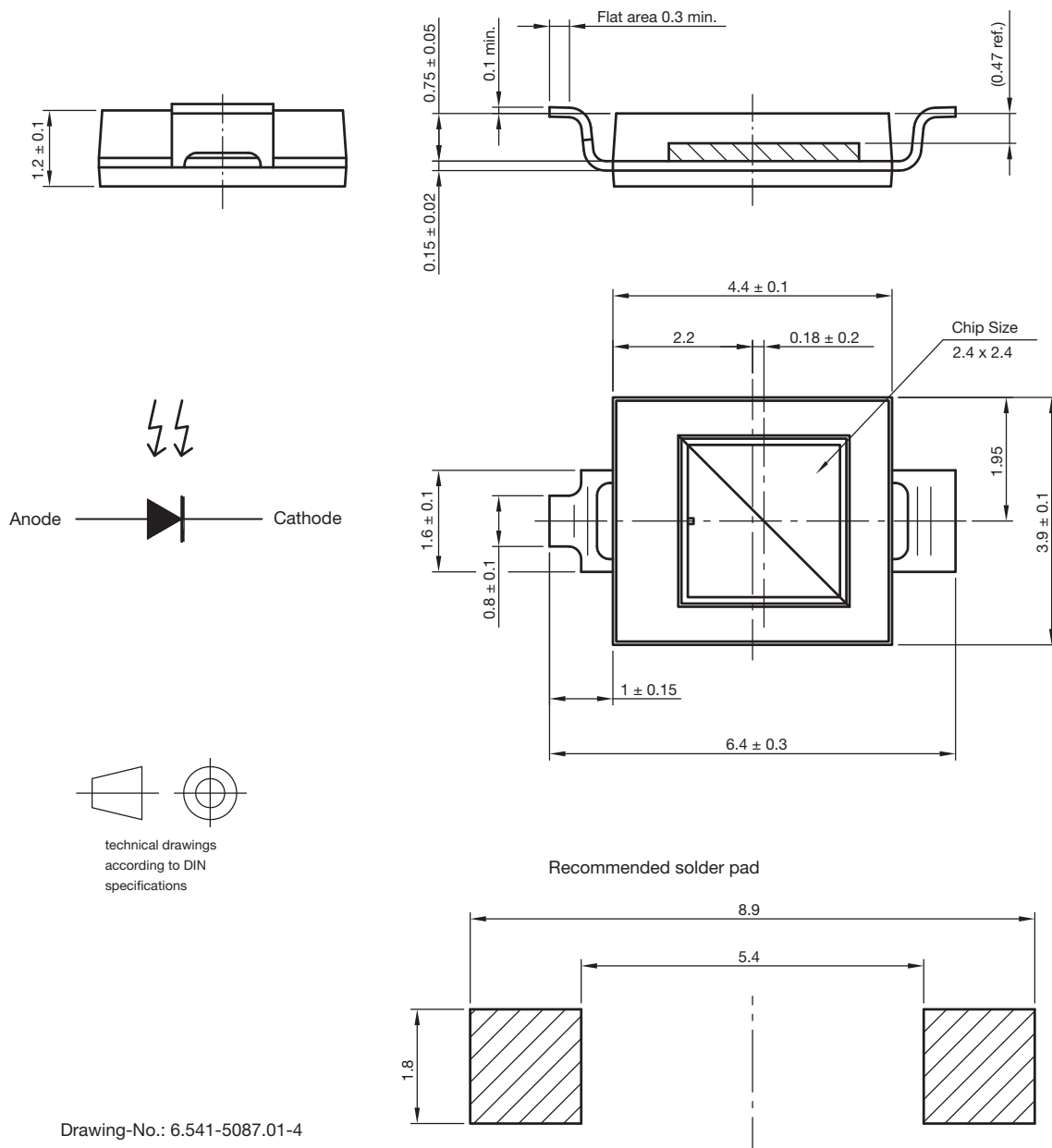
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Issue: 1; 15.04.10

22107



PACKAGE DIMENSIONS FOR VBP104SR in millimeters



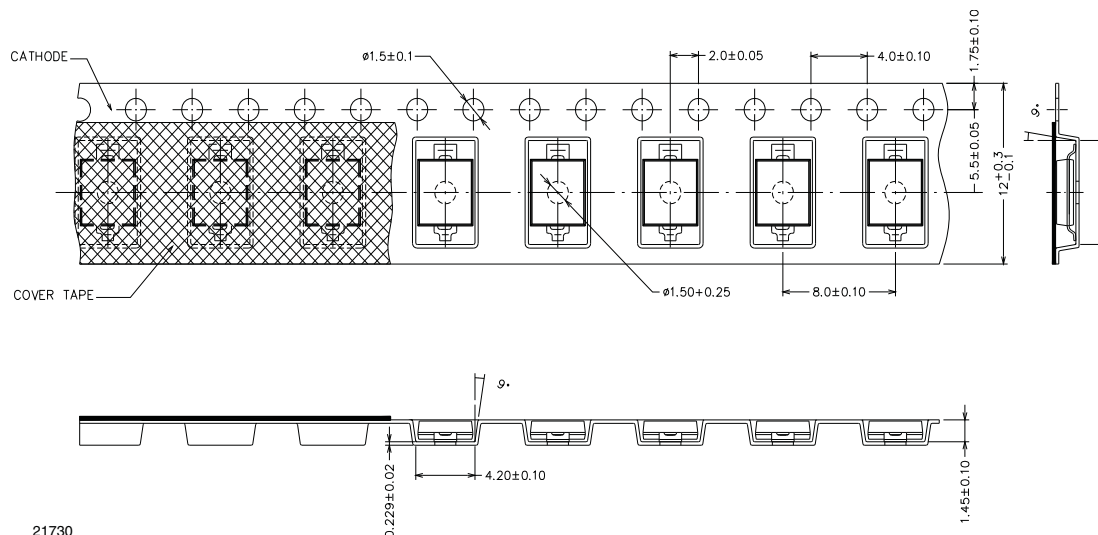
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Issue: 1; 15.04.10

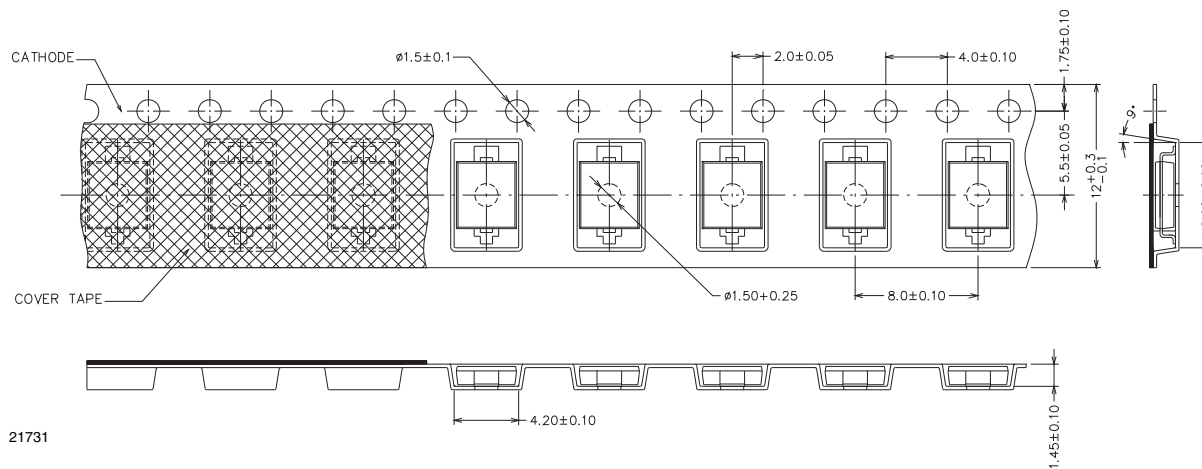
22106

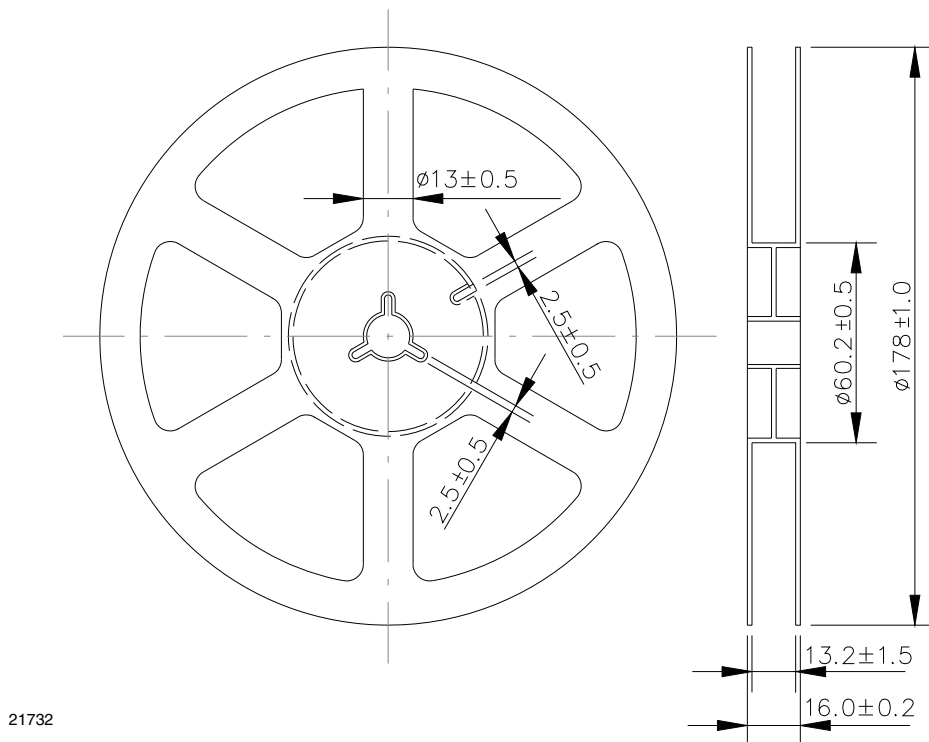


TAPING DIMENSIONS FOR VBP104S in millimeters



TAPING DIMENSIONS FOR VBP104SR in millimeters



REEL DIMENSIONS FOR VBP104S AND VBP104SR in millimeters


21732

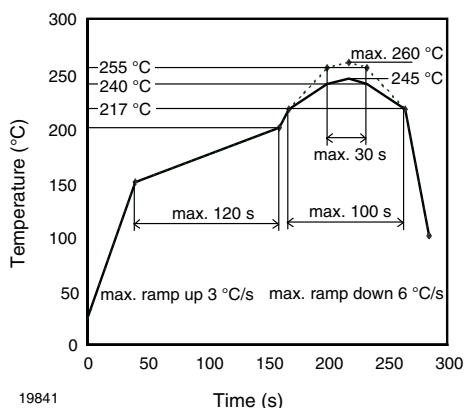
SOLDER PROFILE


Fig. 8 - Lead (Pb)-free Reflow Solder Profile
acc. J-STD-020

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Time between soldering and removing from MBB must not exceed the time indicated in J-STD-020:

Moisture sensitivity: level 3

Floor life: 168 h

Conditions: $T_{amb} < 30\text{ °C}$, $RH < 60\%$

DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or recommended conditions:

192 h at $40\text{ °C} (+ 5\text{ °C})$, $RH < 5\%$

or

96 h at $60\text{ °C} (+ 5\text{ °C})$, $RH < 5\%$.



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